## NSN 5961-01-432-9120



Semiconductor Device Set - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-432-9120 **Inclosure Material:** Metal all transistor **Overall Length:** 0.875 inches all transistor **Terminal Length:** 0.500 inches all transistor and 0.750 inches all transistor **Overall Diameter:** 0.335 inches all transistor and 0.370 inches all transistor **Internal Configuration:** Junction contact all transistor Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 all transistor **Internal Junction Configuration:** Npn all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.016 inches all transistor and 0.021 inches all transistor **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage, dc all transistor and 20.0 collector to emitter voltage, dc all transistor and 3.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 0.40 amperes source cutoff current all transistor **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure:** 

Fiig:

No

A110a0

**Demilitarization:**